

1 Characteristics

Table 1. Absolute maximum ratings ($T_{amb} = 25\text{ }^{\circ}\text{C}$)

| Symbol | Parameter | | Value | Unit |
|-----------|--|--|---------------|--------------------|
| I_{PP} | Peak pulse current ^{(1) (2)} | 10 / 1000 μs | 30 | A |
| I_{TSM} | Non repetitive surge peak on-state current ($F = 50\text{ Hz}$) | $t_p = 10\text{ ms}$ $t = 1\text{ s}$ | 8 3.5 | A |
| T_{stg} | Storage temperature range | | - 40 to + 150 | $^{\circ}\text{C}$ |
| T_j | Maximum junction temperature | | 150 | $^{\circ}\text{C}$ |
| T_L | Maximum lead temperature for soldering during 10s | | 260 | $^{\circ}\text{C}$ |

1. For pulse waveform see [Figure 2](#)
2. See [Figure 7: Test circuit 4 for \$I_{PP}\$ parameter](#)

Figure 2. Pulse waveform

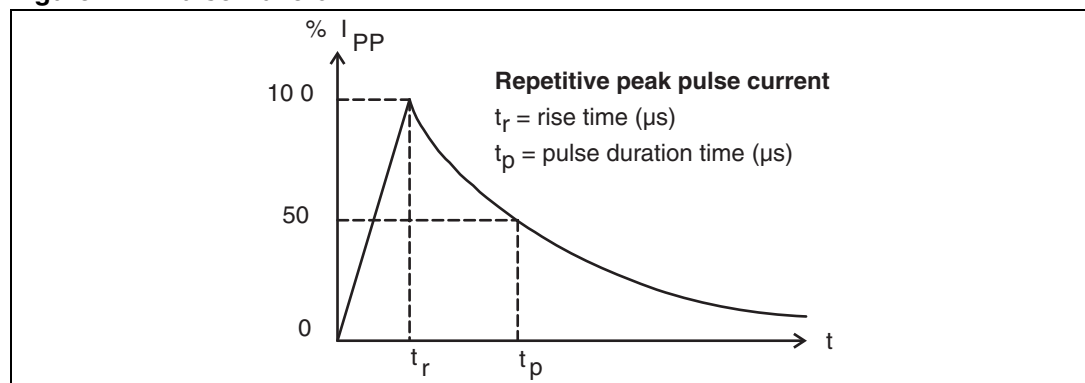


Figure 3. Surge peak current versus overload duration

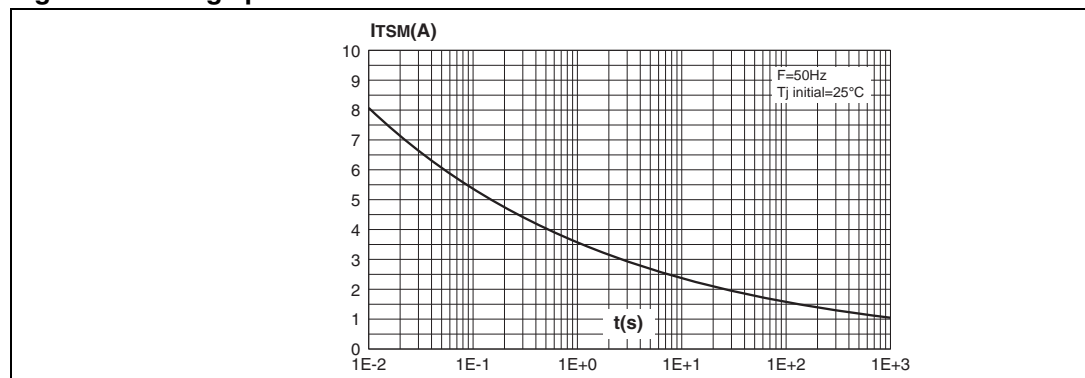


Table 2. Thermal resistance

| Symbol | Parameter | Value | Unit |
|---------------|---------------------|-------|----------------------|
| $R_{th(j-a)}$ | Junction to ambient | 170 | $^{\circ}\text{C/W}$ |

Table 3. Electrical characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$)

| Symbol | Parameter |
|----------|--------------------------------------|
| V_{RM} | Stand-off voltage |
| I_{RM} | Leakage current at stand-off voltage |
| V_R | Continuous reverse voltage |
| V_{BR} | Breakdown voltage |
| V_{BO} | Breakover voltage |
| I_H | Holding current |
| I_{BO} | Breakover current |
| V_F | Forward voltage drop |
| I_{PP} | Peak pulse current |
| C | Capacitance |

Table 4. Static parameters

| Order code | I_{RM} @ V_{RM} | | $I_R^{(1)}$ @ V_R | | $V_{BO}^{(2)}$ @ I_{BO} | | | $I_H^{(3)}$ | $C^{(4)}$ |
|------------|---------------------|-----|---------------------|-----|---------------------------|------|------|-------------|-----------|
| | max. | | max. | | max. | min. | max. | min. | max. |
| | μA | V | μA | V | V | V | mA | mA | pF |
| THBT15011D | 5 | 135 | 50 | 150 | 210 | 50 | 400 | 150 | 80 |
| THBT20011D | 5 | 180 | 50 | 200 | 290 | 50 | 400 | 150 | 80 |
| THBT27011D | 5 | 240 | 50 | 270 | 380 | 50 | 400 | 150 | 80 |

- I_R measured at V_R guarantee $V_{BR} \min \geq V_R$
- Measured at 50 Hz (1 cycle) - See [Figure 4: Test circuit 1 for \$I_{BO}\$ and \$V_{BO}\$ parameters.](#)
- See [Figure 5: Test circuit 2 for dynamic \$I_H\$ parameter.](#)
- $V_R = 1\text{ V}$, $F = 1\text{ MHz}$.

Table 5. Dynamic breakover voltages (transversal mode)

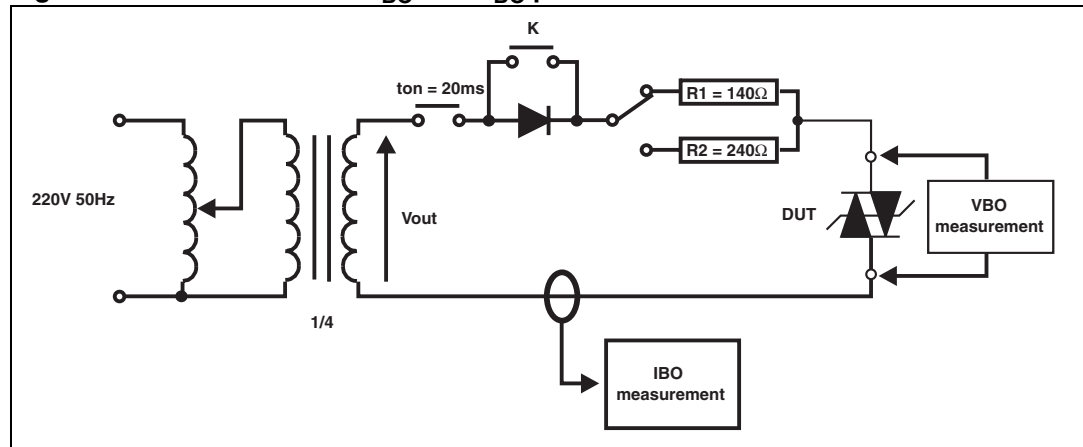
| Type | Symbol | Test conditions ⁽¹⁾ | | | | Max | Unit |
|------------|----------|--------------------------------|--------|--------------------------|------------------------|-----|------|
| THBT15011D | V_{BO} | 10/700 μs | 1.5 kV | $R_p = 10\text{ }\Omega$ | $I_{PP} = 30\text{ A}$ | 190 | V |
| | | 1.2/50 μs | 1.5 kV | $R_p = 10\text{ }\Omega$ | $I_{PP} = 30\text{ A}$ | 190 | |
| | | 2/10 μs | 2.5 kV | $R_p = 62\text{ }\Omega$ | $I_{PP} = 38\text{ A}$ | 200 | |
| THBT20011D | V_{BO} | 10/700 μs | 1.5 kV | $R_p = 10\text{ }\Omega$ | $I_{PP} = 30\text{ A}$ | 270 | V |
| | | 1.2/50 μs | 1.5 kV | $R_p = 10\text{ }\Omega$ | $I_{PP} = 30\text{ A}$ | 270 | |
| | | 2/10 μs | 2.5 kV | $R_p = 62\text{ }\Omega$ | $I_{PP} = 38\text{ A}$ | 280 | |
| THBT27011D | V_{BO} | 10/700 μs | 1.5 kV | $R_p = 10\text{ }\Omega$ | $I_{PP} = 30\text{ A}$ | 360 | V |
| | | 1.2/50 μs | 1.5 kV | $R_p = 10\text{ }\Omega$ | $I_{PP} = 30\text{ A}$ | 360 | |
| | | 2/10 μs | 2.5 kV | $R_p = 62\text{ }\Omega$ | $I_{PP} = 38\text{ A}$ | 400 | |

- See [Figure 6: Test circuit 3 for \$V_{BO}\$ parameters.](#) R_p is the protection resistor located on the line card.

2 Test circuits

2.1 Test procedure for test circuit 1 for I_{BO} and V_{BO} parameters

Figure 4. Test circuit 1 for I_{BO} and V_{BO} parameters



Pulse test duration ($t_p = 20 \text{ ms}$):

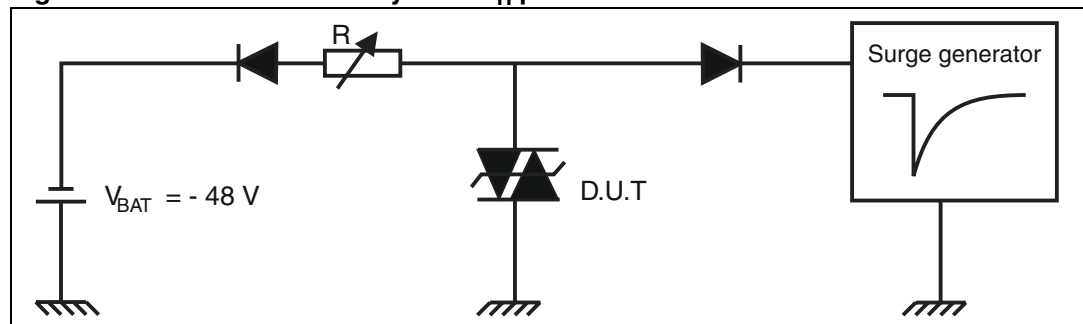
- For bidirectional devices switch K is closed.
- For unidirectional devices switch K is open.

V_{OUT} selection:

- For device with $V_{BO} < 200 \text{ V}$, $V_{OUT} = 250 \text{ V}_{RMS}$, $R1 = 140 \Omega$.
- For device with $V_{BO} \geq 200 \text{ V}$, $V_{OUT} = 480 \text{ V}_{RMS}$, $R2 = 240 \Omega$.

2.2 Test procedure for test circuit 2 for dynamic I_H parameter

Figure 5. Test circuit 2 for dynamic I_H parameter



This is a go no-go test, which can confirm the holding current (I_H) level.

Procedure

1. Adjust the current level at the I_H value by short circuiting the AK of the D.U.T.
2. Fire the D.U.T. with a surge current $I_{PP} = 10\text{A}$, $10/1000\mu\text{s}$.
3. The D.U.T. will come back off-state within 50 ms maximum.

2.3 Test circuit 3 for V_{BO} parameters

Figure 6. Test circuit 3 for V_{BO} parameters

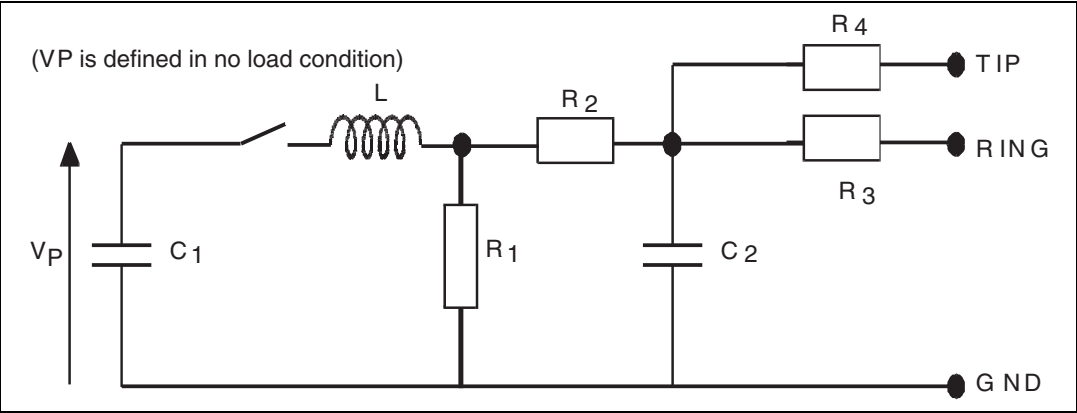
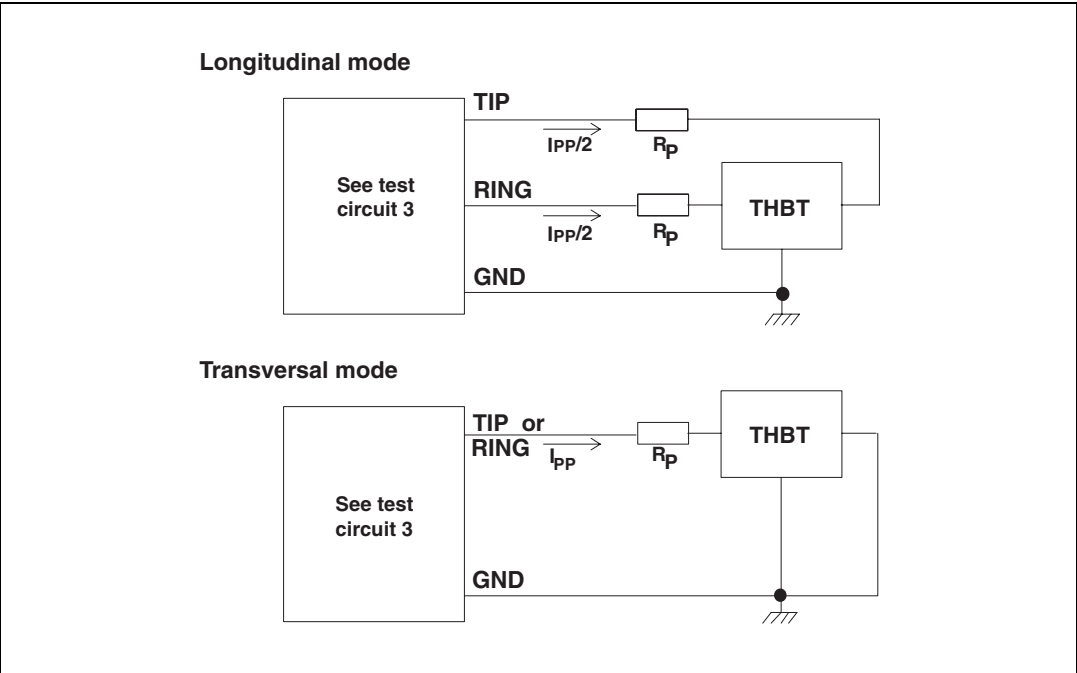


Table 6. Parameters for test circuit 3 for selected pulse characteristics

| Pulse (μ s) | | V_P (V) | C_1 (μ F) | C_2 (nF) | L (μ H) | R_1 (Ω) | R_2 (Ω) | R_3 (Ω) | R_4 (Ω) | I_{PP} (A) | R_p (Ω) |
|------------------|-------|--------------|---------------------|---------------|-------------------|-----------------------|-----------------------|-----------------------|-----------------------|-----------------|-----------------------|
| t_r | t_p | | | | | | | | | | |
| 10 | 700 | 1500 | 20 | 200 | 0 | 50 | 15 | 25 | 25 | 30 | 10 |
| 1.2 | 50 | 1500 | 1 | 33 | 0 | 76 | 13 | 25 | 25 | 30 | 10 |
| 2 | 10 | 2500 | 10 | 0 | 1.1 | 1.3 | 0 | 3 | 3 | 38 | 62 |

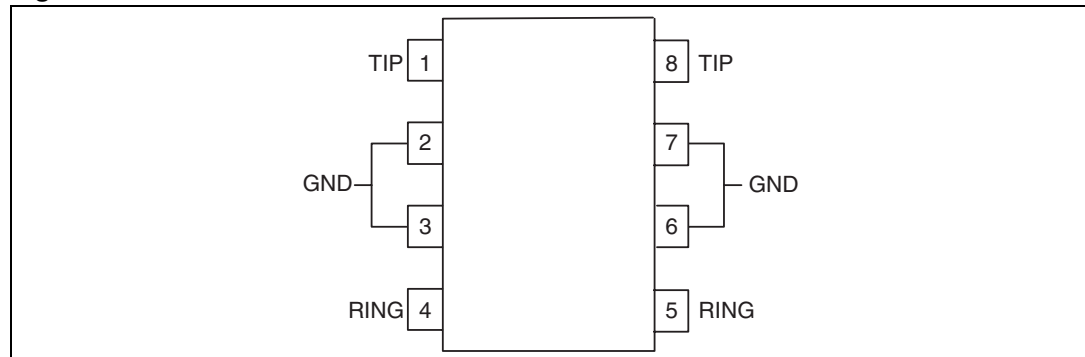
2.4 Test circuit 4 for I_{PP} parameter

Figure 7. Test circuit 4 for I_{PP} parameter



3 Application information

Figure 8. Device connections



Connect pins 2, 3, 6 and 7 to ground to guarantee a good surge current capability for long duration disturbances.

To take advantage of the “4-point” structure of the THBT, the TIP and RING lines have to cross the device. In this case, the device will eliminate the overvoltages generated by the parasitic inductances of the wiring (Ldi/dt), especially for very fast transients.

3.1 Application circuits

Figure 9. Line card protection

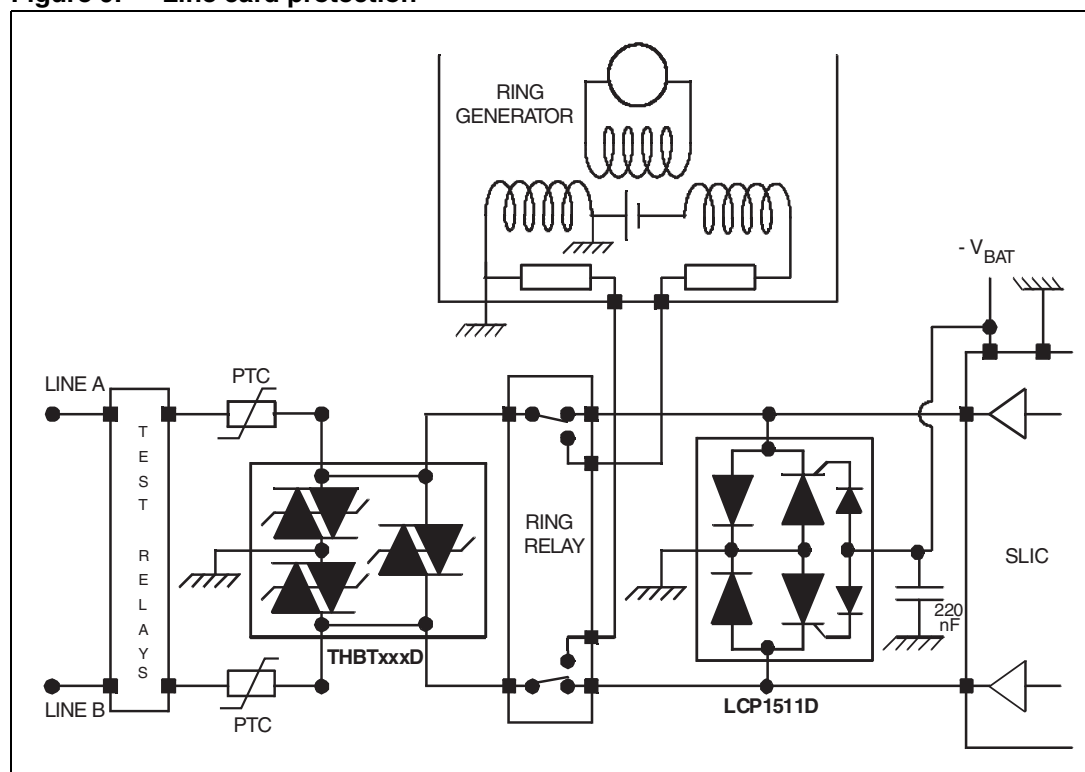
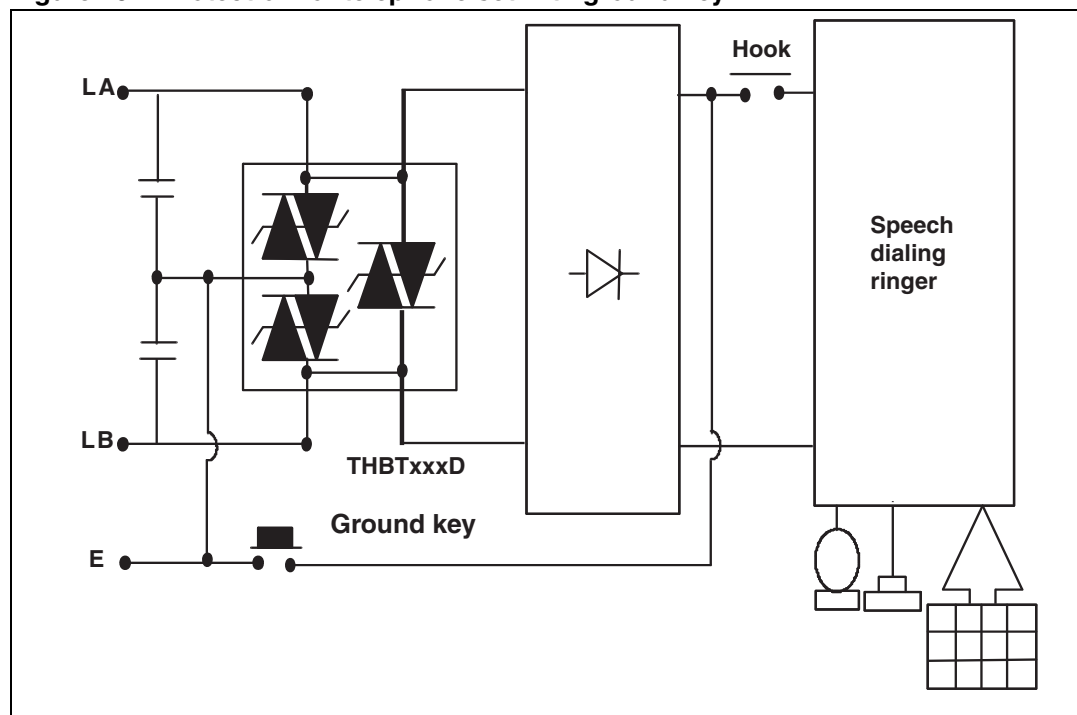
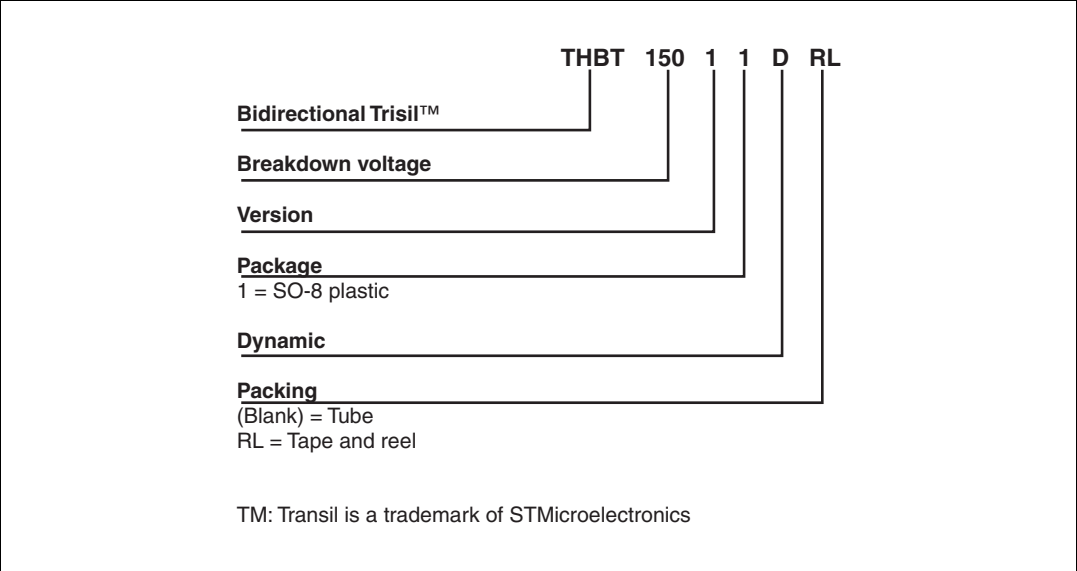


Figure 10. Protection for telephone set with ground key



4 Ordering information scheme

Figure 11. Ordering information scheme



5 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 7. SO-8 dimensions

| Ref. | Dimensions | | | | | |
|------|-------------|------|------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | | | 1.75 | | | 0.069 |
| A1 | 0.1 | | 0.25 | 0.004 | | 0.010 |
| A2 | 1.25 | | | 0.049 | | |
| b | 0.28 | | 0.48 | 0.011 | | 0.019 |
| C | 0.17 | | 0.23 | 0.007 | | 0.009 |
| D | 4.80 | 4.90 | 5.00 | 0.189 | 0.193 | 0.197 |
| E | 5.80 | 6.00 | 6.20 | 0.228 | 0.236 | 0.244 |
| E1 | 3.80 | 3.90 | 4.00 | 0.150 | 0.154 | 0.157 |
| e | | 1.27 | | | 0.050 | |
| h | 0.25 | | 0.50 | 0.010 | | 0.020 |
| L | 0.40 | | 1.27 | 0.016 | | 0.050 |
| L1 | | 1.04 | | | 0.041 | |
| k | 0° | | 8° | 0° | | 8° |
| ppp | | | 0.10 | | | 0.004 |

Figure 12. Footprint, dimensions in mm (inches)

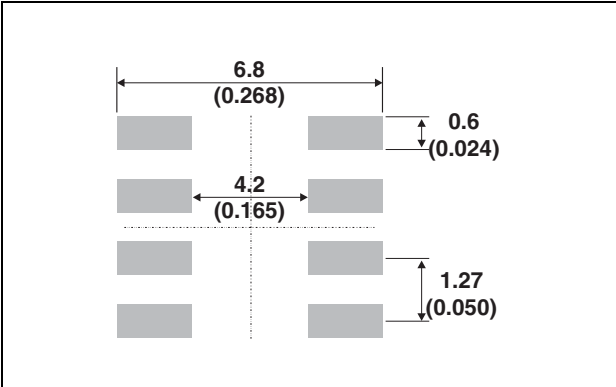
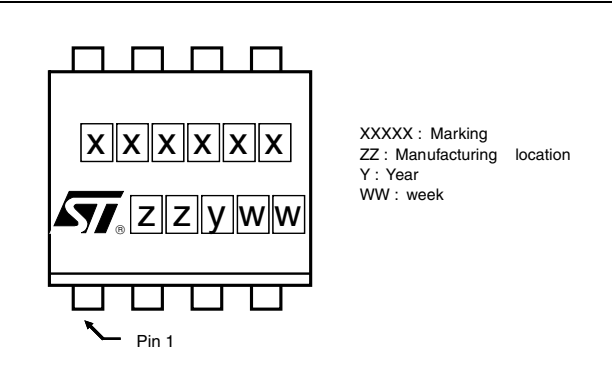


Figure 13. Marking



6 Ordering information

Table 8. Ordering information

| Order code | Marking | Package | Weight |
|------------|---------|---------|---------|
| THBT15011D | BT151D | SO-8 | 0.077 g |
| THBT20011D | BT201D | | |
| THBT27011D | BT271D | | |

7 Revision history

Table 9. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| Oct-2003 | 7A | Previous release |
| 19-Feb-2008 | 8 | Reformatted to current standards. Removed THBT16011D from Table 4 and Table 8 . Updated Figure 4 , Figure 5 , and Figure 9 . Added ECOPACK paragraph in Section 5 . Added Figure 13: Marking . |
| 09-Dec-2010 | 9 | Restructured for conformity with other products in this class. Updated trademark statement for Trisil in Figure 11 . |

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